TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX374F,TC74LVX374FW,TC74LVX374FT

Octal D-Type Flip-Flop with 3-State Output

Note: xxxFW (JEDEC SOP) is not available in Japan.

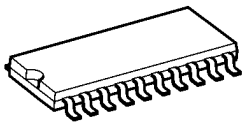
The TC74LVX374F/FW/FT is a high-speed CMOS octal D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

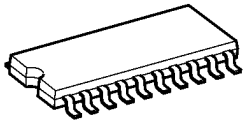
This 8-bit D-type flip-flop is controlled by a clock input (CK) and a output enable input ($\overline{OE}$). When the $\overline{OE}$ input is high, the eight outputs are in a high-impedance state.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

TC74LVX374F



SOP20-P-300-1.27A



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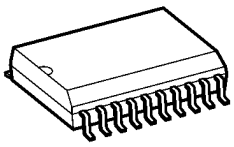
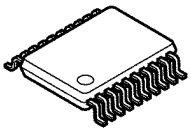
TC74LVX374FW



SOL20-P-300-1.27

TC74LVX374FT



TSSOP20-P-0044-0.65A

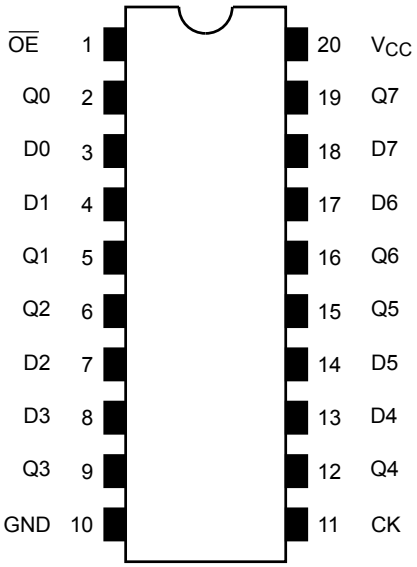
Weight

SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

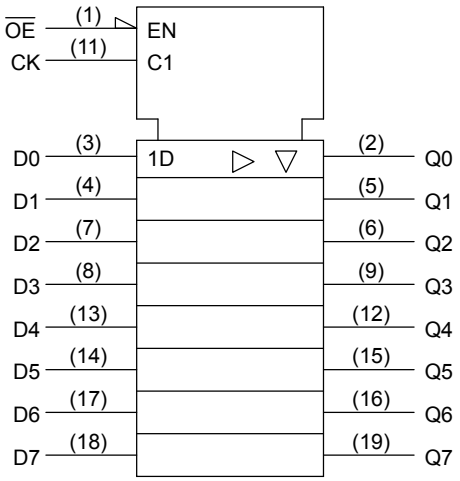
Features

- High-speed: f_{max} = 160 MHz (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- Input voltage level: V_{IL} = 0.8 V (max) (V_{CC} = 3 V)
  V_{IH} = 2.0 V (min) (V_{CC} = 3 V)
- Power-down protection is provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74HC374

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

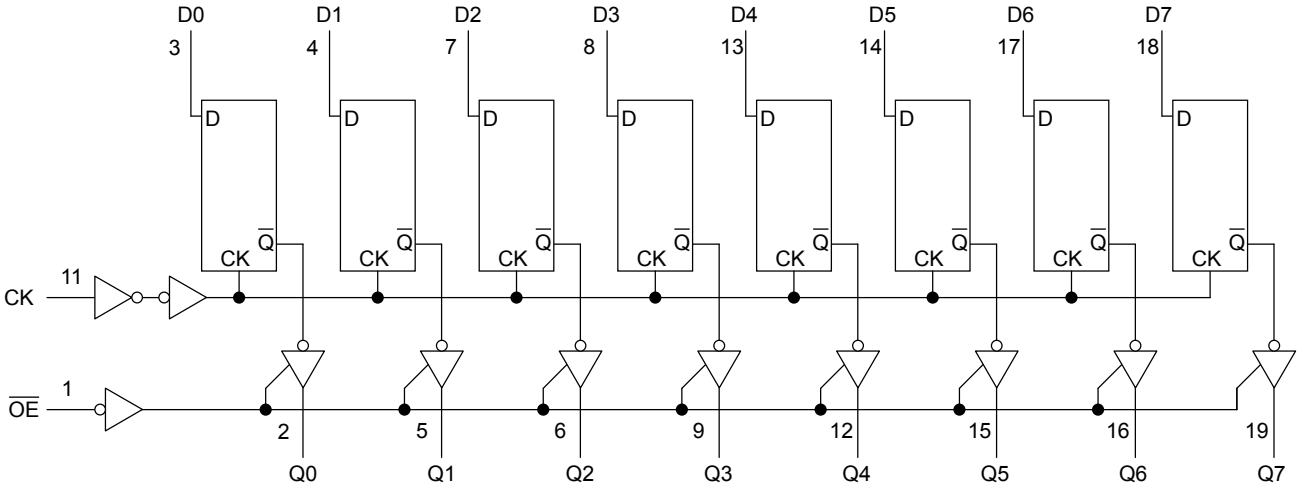
Inputs			Outputs
$\overline{OE}$	CK	D	
H	X	X	Z
L	↓	X	Qn
L	↑	L	L
L	↑	H	H

X: Don't care

Z: High impedance

Qn: No change

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
Input voltage	H-level	V_{IH}	—		2.0	1.5	—	—	1.5	—	V
					3.0	2.0	—	—	2.0	—	
					3.6	2.4	—	—	2.4	—	
	L-level	V_{IL}	—		2.0	—	—	0.5	—	0.5	
					3.0	—	—	0.8	—	0.8	
					3.6	—	—	0.8	—	0.8	
Output voltage	H-level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				I_{OH} = −50 μA	3.0	2.9	3.0	—	2.9	—	
				I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
	L-level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA	3.0	—	0	0.1	—	0.1	
				I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
3-state output Off-state current		I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		3.6	—	—	±0.25	—	±2.5	μA
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		3.6	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	4.0	—	40.0	μA

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Ta = 25°C Limit	Ta = −40 to 85°C Limit	Unit
Minimum pulse width (CK)	$t_{W(H)}$ $t_{W(L)}$	—	2.7	7.5	8.0	ns
			3.3 ± 0.3	5.0	5.5	
Minimum set-up time	t_s	—	2.7	6.5	6.5	ns
			3.3 ± 0.3	4.5	4.5	
Minimum hold time	t_h	—	2.7	2.0	2.0	ns
			3.3 ± 0.3	2.0	2.0	

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t_{pLH}	—	2.7	15	—	8.5	16.3	1.0	19.5	ns
				50	—	11.0	19.8	1.0	23.0	
	t_{pHL}		3.3 ± 0.3	15	—	6.7	10.6	1.0	12.5	
				50	—	9.2	14.1	1.0	16.0	
Output enable time	t_{pZL}	R_L = 1 kΩ	2.7	15	—	7.6	14.5	1.0	17.5	ns
				50	—	10.1	18.0	1.0	21.0	
	t_{pZH}		3.3 ± 0.3	15	—	5.9	9.3	1.0	11.0	
				50	—	8.4	12.8	1.0	14.5	
Output disable time	t_{pLZ}	R_L = 1 kΩ	2.7	50	—	11.5	18.5	1.0	22.0	ns
	t_{pHZ}		3.3 ± 0.3	50	—	9.6	13.2	1.0	15.0	
Maximum clock frequency	f_{max}	—	2.7	15	60	115	—	50	—	MHz
				50	45	60	—	40	—	
			3.3 ± 0.3	15	100	160	—	85	—	
				50	60	95	—	55	—	
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
			3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C_{IN}	(Note 2)			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note 3)			—	32	—	—	—	pF

Note 1: Parameter guaranteed by design.
($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

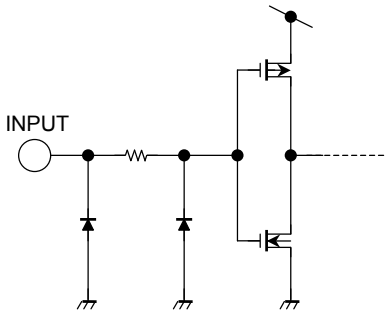
Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F)
And the total C_{PD} when n pcs. of Flip Flop operate can be gained by the following equation:
C_{PD} (total) = 20 + 12·n

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

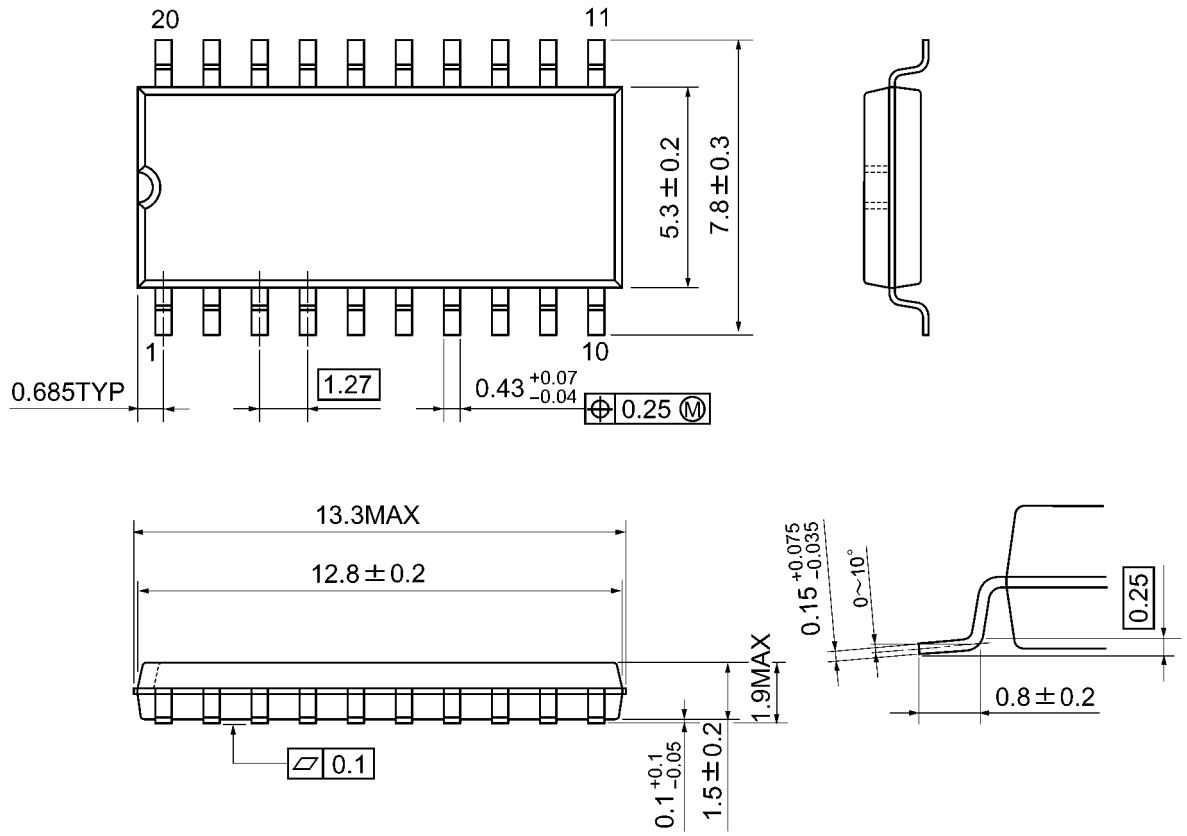
Characteristics	Symbol	Test Condition		Typ.	Limit	Unit
			V_{CC} (V)			
Quiet output maximum dynamic V_{OL}	V_{OLP}	—	3.3	0.5	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	—	3.3	−0.5	−0.8	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	—	3.3	—	2.0	V
Maximum low level dynamic input voltage V_{IL}	V_{ILD}	—	3.3	—	0.8	V

Input Equivalent Circuit



Package Dimensions

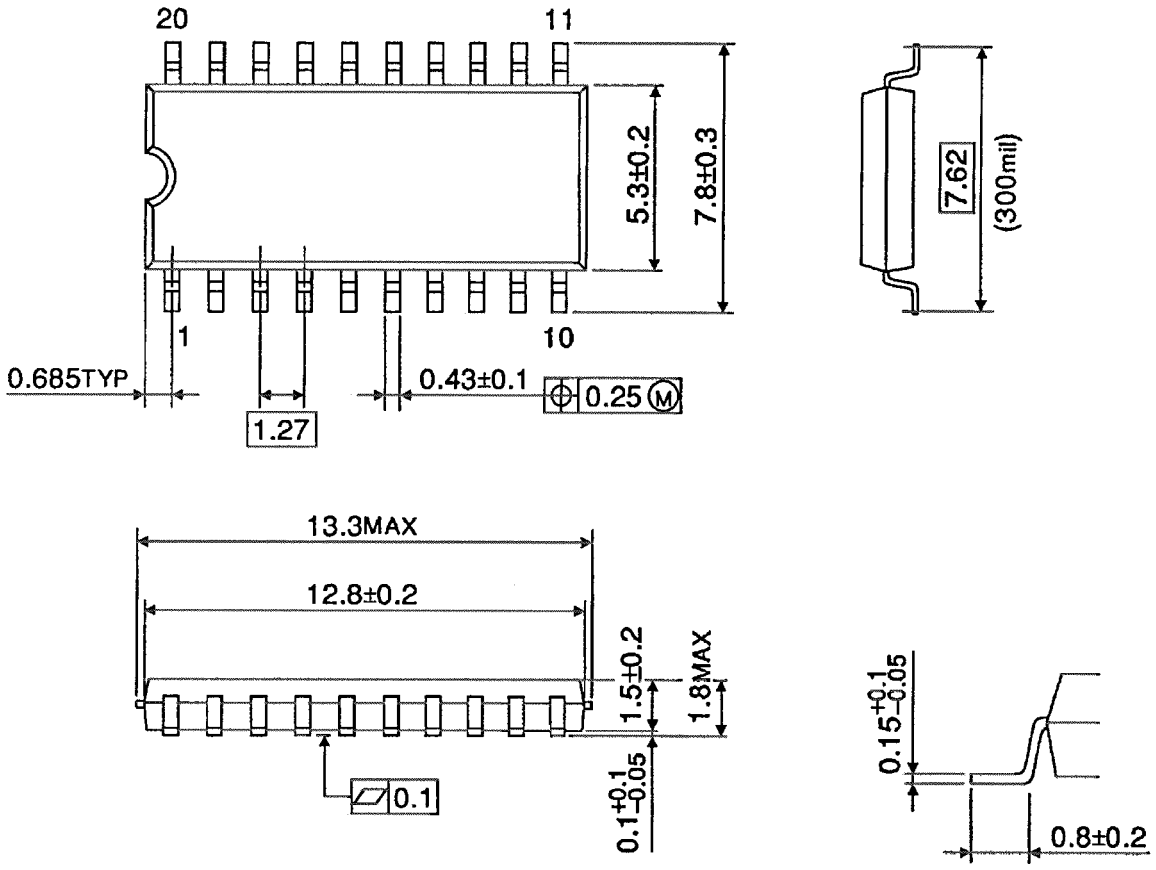
SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

Package Dimensions

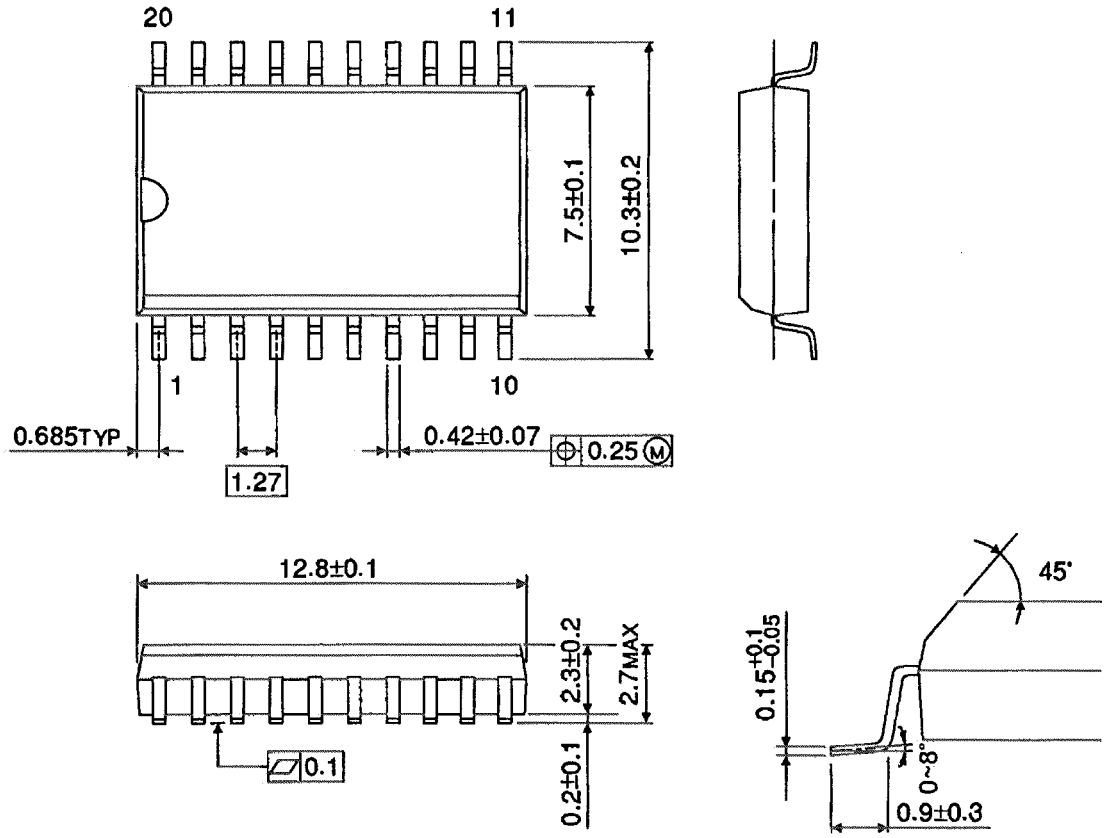
SOP20-P-300-1.27 Unit : mm



Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27 Unit : mm

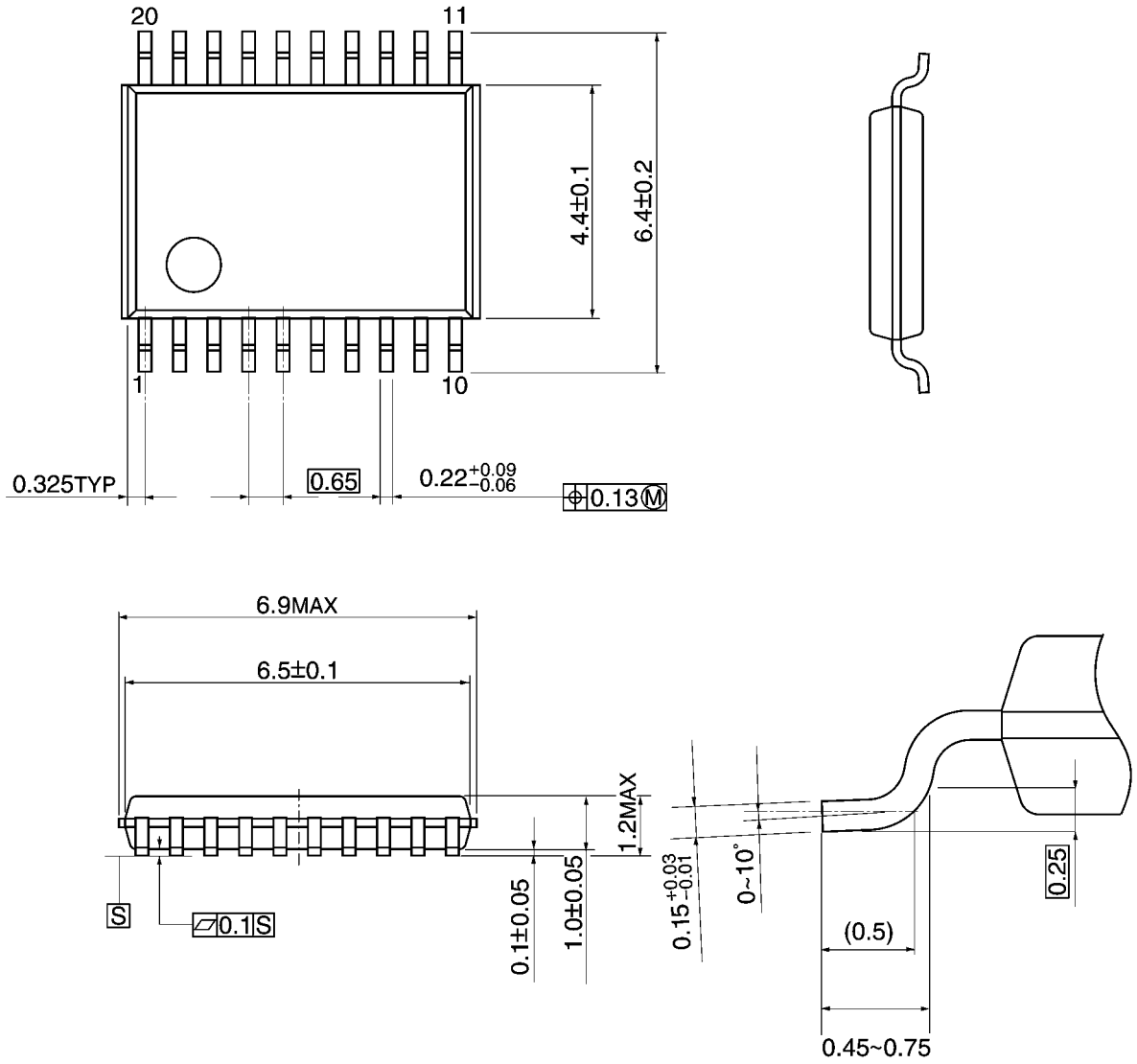


Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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